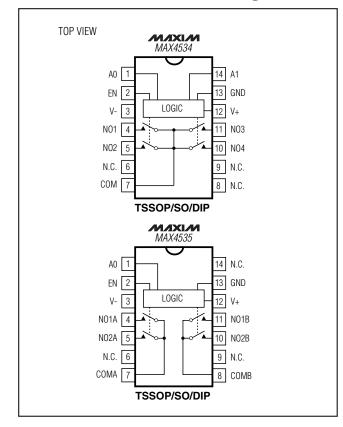
## **General Description**

The MAX4534 (single 4-to-1) and MAX4535 (dual 2-to-1) fault-protected multiplexers operate with ±4.5V to ±20V dual supplies or a +9V to +36V single supply. These multiplexers feature fault-protected inputs, rail-to-rail signal-handling capability, and overvoltage clamping at 150mV beyond the rails. Both parts feature ±40V overvoltage protection with supplies off and ±25V protection with supplies on. On-resistance is 400 $\Omega$  max and is matched between channels to 10 $\Omega$  max. All digital inputs have TTL logic thresholds, ensuring TTL/CMOS-logic compatibility when using a single +12V or dual ±15V supplies.

### **Applications**

Data-Acquisition Systems Industrial and Process Control Avionics Signal Routing

Redundant/Backup Systems



### Pin Configurations

#### **Features**

- ±40V Fault Protection with Power Off
  ±25V Fault Protection with ±15V Supplies
- No Power-Supply Sequencing Required
- All Channels Off with Power Off
- Rail-to-Rail Signal Handling
- Output Clamped to Appropriate Supply Voltage During Fault Condition
- 1.0kΩ typ Output Clamp Resistance During Overvoltage
- 400Ω max On-Resistance
- ♦ 20ns typ Fault Response Time
- ±4.5V to ±20V Dual Supplies
  +9V to +36V Single Supply
- TTL/CMOS-Compatible Logic Inputs

# **Ordering Information**

PART	TEMP RANGE	PIN-PACKAGE
MAX4534CUD	0°C to +70°C	14 TSSOP
MAX4534CSD	0°C to +70°C	14 Narrow SO
MAX4534CPD	0°C to +70°C	14 Plastic DIP
MAX4534EUD	-40°C to +85°C	14 TSSOP
MAX4534ESD	-40°C to +85°C	14 Narrow SO
MAX4534EPD	-40°C to +85°C	14 Plastic DIP
MAX4535CUD	0°C to +70°C	14 TSSOP
MAX4535CSD	0°C to +70°C	14 Narrow SO
MAX4535CPD	0°C to +70°C	14 Plastic SO
MAX4535EUD	-40°C to +85°C	14 TSSOP
MAX4535ESD	-40°C to +85°C	14 Narrow SO
MAX4535EPD	-40°C to +85°C	14 Plastic DIP

### 

Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

# **ABSOLUTE MAXIMUM RATINGS**

(Voltages Referenced to GND)

Continuous Power Dissipation (T <sub>A</sub> = +70°C) 14-Pin TSSOP (derate 6.3mW/°C above +70°C)500mW 14-Pin Narrow SO (derate 8mW/°C above +70°C)640mW
14-Pin Plastic DIP (derate 10mW/°C above +70°C)800mW
Operating Temperature Ranges
MAX453_C_D0°C to +70°C
MAX453_E_D40°C to +85°C
Storage Temperature Range65°C to +150°C
Lead Temperature (soldering, 10s)+300°C

Note 1: COM\_, EN, and A\_ pins are not fault protected. Signals on COM\_, EN, or A\_ exceeding V+ or V- are clamped by internal diodes. Limit forward diode current to maximum current rating.

**Note 2:** NO\_ pins are fault-protected. Signals on NO\_ exceeding -25V to +25V may damage the device during power-on conditions. When the power is off the maximum voltage range is -40V to +40V.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

# **ELECTRICAL CHARACTERISTICS**—Dual Supplies

(V+ = +15V, V- = -15V, V<sub>A\_H</sub> = V<sub>ENH</sub> = 2.4V, V<sub>A\_L</sub> = V<sub>ENL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH								
Fault-Free Analog Signal Range	V <sub>NO</sub> _	Applies with power on or off			V-		V+	V
On-Resistance	Devi		1~^	+25°C		275	400	Ω
OII-Resistance	RON	$V_{COM} = \pm 10V, I_{NO}$	_ = 111A	C, E			500	52
On-Resistance Match Between	ΔR <sub>ON</sub>	$V_{000} = \pm 10V_{00}$	- 1mA	+25°C		2	10	Ω
Channels (Note 4)	ANON	$V_{COM} = \pm 10V, I_{NO}$		C, E			15	52
NO_ Off-Leakage Current		$V_{\rm MO} = 10V/V_{\rm MO}$	10\/	+25°C	-0.5	0.01	0.5	۳۸
(Note 5)	INO_(OFF)	$V_{NO} = \pm 10V, V_{COM}$	[_ = +10V	C, E	-5		5	- nA
		V <sub>COM</sub> _ = ±10V, V <sub>NO</sub> _ = ∓10V	MAX4534	+25°C	-2	0.05	2	- nA
COM_ Off-Leakage Current				C, E	-60		60	
(Note 5)	ICOM_(OFF)		MAX4535	+25°C	-1	0.05	1	
				C, E	-30		30	
		$V_{COM_} = \pm 10V,$ $V_{NO_} = floating$	MAX4534	+25°C	-2	0.1	2	nA
COM_ On-Leakage Current	ICOM_(ON)			C, E	-80		80	
(Note 5)			MAX4535	+25°C	-1	0.1	1	
			IVIAA4555	C, E	-40		40	1
FAULT PROTECTION			I.					
Fault-Protected Analog Signal	1/110	Applies with power of	on		-25		+25	v
Range (Note 6)	V <sub>NO</sub> _	Applies with power of	off		-40		+40	v
COM_ Output Leakage Current,	10014	V <sub>NO</sub> = ±25V, V <sub>EN</sub> =	$0 V_{00} = 0$	+25°C	-20		20	nA
Supplies On	ICOM_	VNU ±23V, VEN =	$0, VCOM_ = 0$	C, E	-1		1	μA

MAX4534/MAX4535

# **ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)**

(V+ = +15V, V- = -15V, V<sub>A\_H</sub> = V<sub>ENH</sub> = 2.4V, V<sub>A\_L</sub> = V<sub>ENL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MAX</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONE	CONDITIONS		MIN	TYP	MAX	UNITS	
NO_ Input Leakage Current,		V <sub>NO_</sub> = ±25V, V(	COM = ∓10V,	+25°C	-20		20		
Supplies On	I <sub>NO</sub> _	$V_{\rm EN} = 0$	_	C, E	-200		200	nA	
NO_ Input Leakage Current,	hie	$V_{NO} = \pm 40V, V_{COM} = 0,$		+25°C	-20		20	nA	
Supplies Off	I <sub>NO</sub> _	V + = 0, V - = 0		C, E	-5		5	μA	
COM_ On Clamp Output	loon	$V_{\rm NO} = +25V V_{\rm O}$	COM_ = 0	+25°C	7	10	13	mA	
Current, Supplies On	ICOM_	$V_{NO} = -25V V_{C}$	OM_ = 0	+23 0	-13	-11	-7		
COM_ On Clamp Output	R <sub>COM</sub> _	V <sub>NO_</sub> = ±25V		+25°C	0.1	1.0	2.5	kΩ	
Resistance, Supplies On		VNO_ = ±20V		C, E	0.08		3	1132	
± Fault Response Time		$R_L = 10k\Omega, V_{NO}$				20		ns	
± Fault Recovery Time		$R_L = 10k\Omega, V_{NC}$	_ = ±25V			2.5		μs	
Fault Trip Threshold		$R_L = 1k\Omega$			V 400	V-	+ + 400	mV	
LOGIC INPUT	-								
Input Logic Voltage High	Va_h, Venh				2.4			V	
Input Logic Voltage Low	VA_L, VENL						0.8	V	
Input Logic Current	I <sub>A_</sub> , I <sub>EN</sub>	$V_{A_{-}} = V_{EN} = 0.8V \text{ or } 2.4V$			-1		1	μA	
SWITCH DYNAMIC CHARACTE	RISTICS								
Enable Turn-On Time	ton	$V_{NO_{-}} = \pm 10V, R_{L} = 1k\Omega,$		+25°C		135	275	ns	
Enable Turn-On Time t <sub>ON</sub>		Figure 3		C, E			400	- 115	
Enable Turn-Off Time	tOFF	$V_{\rm NO}$ = ±10V, R <sub>L</sub> = 1k $\Omega$ ,		+25°C C, E		60	200	- ns	
	UFF	Figure 3	Figure 3				250		
Transition Time	<b>t</b> TRANS	Figure 2		+25°C		130	350	- ns	
	INANO			C, E			500		
Break-Before-Make Time Delay	tBBM	V <sub>NO</sub> _ = ±10V, R Figure 4	$L = 1 k\Omega$ ,		10	60		ns	
Charge Injection (Note 7)	Q	$C_L = 1nF, V_{NO} = 0, R_S = 0,$ Figure 5				1	10	рС	
Off-Isolation (Note 8)	VISO	$R_L = 50\Omega$ , V <sub>NO</sub> = 1V <sub>RMS</sub> , f = 1MHz, Figure 6				-62		dB	
Channel-to-Channel Crosstalk (Note 9)	V <sub>CT</sub>	$R_L = 50\Omega$ , $V_{NO} = 1V_{RMS}$ , f = 1MHz, Figure 7				-53		dB	
NO_Off-Capacitance	C <sub>NO_(OFF)</sub>	f = 1MHz, Figure 8				5		pF	
		f = 1MHz,	MAX4534			6.5			
COM_ Off-Capacitance	CCOM_(OFF)	Figure 8 MAX4535				4		рF	
COM On Capacitance	Cook	f = 1MHz,	MAX4534			13.5		٣Ē	
COM_ On-Capacitance	CCOM_(ON)	Figure 8	· · · · · · · · · · · · · · · · · · ·			10.5		pF	



### **ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)**

(V+ = +15V, V- = -15V, VA\_H = VENH = 2.4V, VA\_L = VENL = 0.8V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at TA = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
POWER SUPPLY							
Power-Supply Range	V+, V-			±4.5		±20	V
		$A \parallel V = V \equiv 0 = 0 = 5 V$	+25°C		225	400	
V. Supply Current	+	All $V_{A_{-}} = V_{EN} = 0$ or 5V	С, Е			600	μA
V+ Supply Current	1+	All $V_{A_{-}} = V_{EN} = 0$ or 15V	+25°C		125	200	
			С, Е			300	
V. Oursela Ourseat	-	All $V_{A_{-}} = V_{EN} = 0, 5V, \text{ or } 15V$	+25°C		125	200	- μΑ
V- Supply Current	1-		С, Е			300	
GND Supply Current			+25°C		0.01	1	
		All $V_{A_{-}} = V_{EN} = 0$ or 15V	С, Е			10	1
	IGND		+25°C		100	200	μA
		All $V_{A_{-}} = V_{EN} = 5V$	C, E			300	1

### ELECTRICAL CHARACTERISTICS—Single +12V Supply

(V+ = +12V, V- = 0, V<sub>A\_H</sub> = V<sub>ENH</sub> = 2.4V, V<sub>A\_L</sub> = V<sub>ENL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MIN</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS		TA	MIN	TYP	MAX	UNITS						
Fault-Free Analog Signal Range	V <sub>NO</sub>	Applies with pov	ver on or off		0		V+	V						
On-Resistance	Ron	$V_{COM} = 10V, I_N$		+25°C		650	950	Ω						
On-nesistance	non	$VCOM_ = 10V, IN$	IO_ = 500µA	C, E			1100	52						
On-Resistance Match Between	ADau	Veen 10V II	EOOUA	+25°C		10	25							
Channels (Note 5)	ΔR <sub>ON</sub>	$V_{COM} = 10V, I_{NO} = 500\mu A$		C, E			40	Ω						
NO_ Off-Leakage Current	his (SEE)	DFF) V <sub>COM</sub> = 10V, 1V; V <sub>NO</sub> = 1V, 10V		+25°C	-0.5	0.01	0.5	- nA						
(Notes 5, 10)	I <sub>NO_(OFF)</sub>			C, E	-10		10							
	ICOM_(OFF)	V <sub>COM</sub> = 10V,	= 10V, MAX4534	+25°C	-2		2							
COM_ Off-Leakage Current				C, E	-60		60							
(Notes 5, 10)		COM_(OFF)	1V; V <sub>NO</sub> _ = 1V, 10V MAX4535	1	,	/ /		,	= 1V. 10V	+25°C	-1		1	nA
				IVIAA4555	C, E	-30		30						
COM_ On-Leakage Current (Notes 5, 10)		$V_{COM} = 10V,$		+25°C	-2		2							
		1V; V <sub>NO</sub> = 10V,	MAX4534	C, E	-80		80							
	ICOM_(ON)		MAX4535	+25°C	-1		1	nA						
		1V, or floating	101/4/1000	C, E	-40		40	1						

# ELECTRICAL CHARACTERISTICS—Single +12V Supply (continued)

(V+ = +12V, V- = 0, V<sub>A\_H</sub> = V<sub>ENH</sub> = 2.4V, V<sub>A\_L</sub> = V<sub>ENL</sub> = 0.8V, T<sub>A</sub> = T<sub>MIN</sub> to T<sub>MIN</sub>, unless otherwise noted. Typical values are at T<sub>A</sub> = +25°C.) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
FAULT PROTECTION		1		1			I
Fault-Protected Analog Signal		Applies with all power on	+25°C	-25		25	
Range (Note 6)	V <sub>NO</sub> _	Applies with all power off +2		-40		40	V
COM_ Output Leakage Current,	laav	$V_{\rm NO}$ = ±25V,	+25°C	-20		20	nA
Supply On	ICOM_	$V_{COM} = 0$	C, E	-1		1	μA
NO_ Input Leakage Current,	hie	$V_{NO} = \pm 25V, V_{COM} = 0,$	+25°C	-20		20	nA
Supply On	I <sub>NO</sub> _	$V_{NO} = \pm 23V$ ; $V_{COM} = 0$ ,	C, E	-5		5	μΑ
NO_ Input Leakage Current,	luo.	$V_{NO} = \pm 40V, V + = 0$	+25°C	-20	0.1	20	nA
Supply Off	I <sub>NO</sub> _	VNO 140V, V+ - 0	C, E	-5		5	μΑ
COM_ ON Output Current, Supply On	ICOM_	V <sub>NO</sub> _ = 25V	+25°C	2	3	5	nA
COM_ ON Output Resistance, Supply On	R <sub>COM</sub> _	V <sub>NO_</sub> = 25V	+25°C		2.4	6	kΩ
Fault Trip Threshold		$R_L = 1k\Omega$		V 400	V	+ + 400	mV
LOGIC INPUT	1	1					
Input Logic Voltage High	V <sub>A_H,</sub> V <sub>ENH</sub>			2.4			V
ANALOG SWITCH							
Input Logic voltage Low	V <sub>ENL</sub>					0.8	V
Input Logic Current	I <sub>A_</sub> , I <sub>EN</sub>	$V_{A_{-}} = V_{EN} = 0.8V \text{ or } 2.4V$		-1		1	μA
SWITCH DYNAMIC CHARACTE	RISTICS	1					
Enable Turn-On Time	tou	$V_{COM}$ = 10V, $R_L$ = 2k $\Omega$ ,	+25°C		220	500	20
Enable full-On fille	ton	Figure 3	C, E			700	ns
Enable Turn-Off Time	torr	$V_{COM}$ = 10V, $R_L$ = 2k $\Omega$ ,	+25°C		100	250	ns
	toff	Figure 3	C, E			350	115
Break-Before-Make Time Delay	<sup>t</sup> BBM	$V_{COM_{-}} = 10V, R_{L} = 2k\Omega,$ Figure 4	+25°C	50	100		ns
Charge Injection (Note 7)	Q	$C_L = 1nF, V_{NO} = 0, R_S = 0,$ Figure 5 +25°C			2	10	рС
Off-Isolation (Note 8)	V <sub>ISO</sub>	$R_L = 50\Omega$ , $V_{NO_{-}} = 1V_{RMS}$ , f = 1MHz, Figure 6		-62		dB	
Channel-to-Channel Crosstalk (Note 9)	V <sub>CT</sub>	$R_L = 50\Omega$ , $V_{NO} = 1V_{RMS}$ , f = 1MHz, Figure 7			-65		dB

### ELECTRICAL CHARACTERISTICS—Single +12V Supply (continued)

 $(V_{+} = +12V, V_{-} = 0, V_{A_H} = V_{ENH} = 2.4V, V_{A_L} = V_{ENL} = 0.8V, T_A = T_{MIN}$  to  $T_{MIN}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .) (Note 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
POWER SUPPLY	•						
Power-Supply Range	V+			9		36	V
V+ Supply Current		All $V_{A}$ = $V_{EN}$ = 0 or 12V	+25°C		75	150	
			C, E			250	
	1+	All $V_{A}$ = $V_{EN}$ = 5V	+25°C		150	275	μΑ
			C, E			375	

Note 3: Algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 4:  $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$ .

**Note 5:** Leakage parameters are 100% tested at maximum-rated hot temperature and guaranteed by correlation at T<sub>A</sub> = 25°C.

**Note 6:** NO\_ pins are fault protected, and COM\_ pins are not fault protected. The max input voltage, on NO\_ pins, depends upon the COM\_ load configuration. Generally, the max input voltage is ±25V, with ±15V supplies, and a load referred to ground. For more detailed information, see the *NO\_ Input Voltage section*.

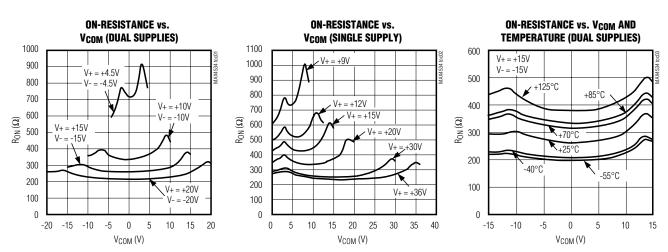
**Note 7:** Guaranteed by design.

**Note 8:** Off-isolation = 20 log10 ( $V_{COM}$  /  $V_{NO}$ ),  $V_{COM}$  = output,  $V_{NO}$  = input to off switch.

Note 9: Between any two analog inputs.

Note 10: Leakage testing for single-supply operation is guaranteed by testing with dual supplies.

(V+ = +15V, V- = -15V,  $T_A$  = +25°C, unless otherwise noted.)



# **Typical Operating Characteristics**



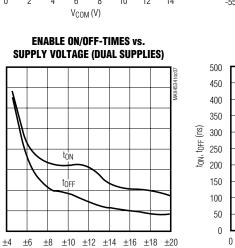
### **Typical Operating Characteristics (continued)**

Q (pC)

 $(V + = +15V, V - = -15V, T_A = +25^{\circ}C, unless otherwise noted.)$ 

**TEMPERATURE (SINGLE SUPPLY)** 1000 1μ 900 -125°C 100n 800 +85°C 10n 700 -70°( 1n 1000 1000 Ron (Ω) 600 +25°C 500 40°0 400 300 -55°C 10p 200 V+ = +12V 1р 100 V- = 0 0 0.1p 0 2 4 6 8 10 12 14 -55 V<sub>COM</sub> (V)

**ON-RESISTANCE vs. VCOM AND** 



400

350

300

<sup>100</sup>, toff (ns) 150 250

150

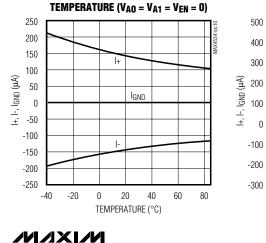
100

50

0

**POWER-SUPPLY CURRENT vs.** 

SUPPLY VOLTAGE (V)



**LEAKAGE CURRENT vs. TEMPERATURE** ICOM\_ON ICOM\_OFF INO\_OFF -30 -5 20 45 70 95 120 145 TEMPERATURE (°C)

**ENABLE ON/OFF-TIMES vs.** 

SUPPLY VOLTAGE (SINGLE SUPPLY)

SUPPLY VOLTAGE (V)

**POWER-SUPPLY CURRENT vs.** 

TEMPERATURE (VA0 = VA1 = VEN = 5V)

|+

20 40 60 80

TEMPERATURE (°C)

IGND<sup>-</sup>

5 10 15 20 25 30 35

500

400

300

0

-100

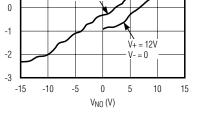
-200

-300

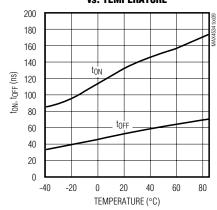
-40 -20 0 ton

toFF

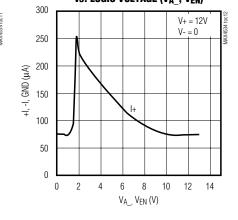
CHARGE INJECTION vs. V<sub>NO</sub> (DUAL AND SINGLE SUPPLIES) 4 3 2 V+ = +15V 1 V- = -15V 0



**ENABLE ON/OFF-TIMES** vs. TEMPERATURE



**POWER-SUPPLY CURRENT** vs. LOGIC VOLTAGE (VA , VEN)



MAX4534/MAX4535

7



500

400

300

200

100

-100

-250

-300

0 2 4 6 8 10 12

0

+l, -l, GND (μA)

#### \_Typical Operating Characteristics (continued)

 $(V + = +15V, V - = -15V, T_A = +25^{\circ}C, unless otherwise noted.)$ 

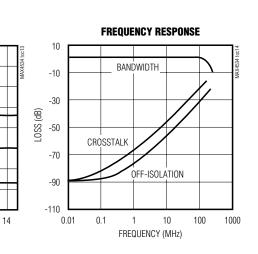
GND

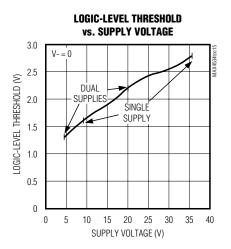
١.

**POWER-SUPPLY CURRENT** 

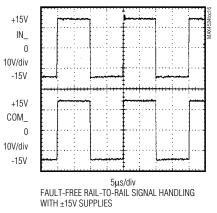
vs. LOGIC VOLTAGE (VA , VEN)

VA\_, VEN (V)

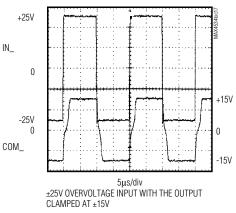




FAULT-FREE SIGNAL PERFORMANCE



**INPUT OVERVOLTAGE vs. OUTPUT CLAMPING** 



### \_Pin Descriptions

PIN	NAME	FUNCTION
1	A0	Address Bit 0
2	EN	Enable Input
3	V-	Negative Supply Voltage
4	NO1	Channel Input 1 (fault protected)
5	NO2	Channel Input 2 (fault protected)
6, 8, 9	N.C.	No connection
7	COM	Analog Output
10	NO4	Channel Input 4 (fault protected)
11	NO3	Channel Input 3 (fault protected)
12	V+	Positive Supply Voltage
13	GND	Ground
14	A1	Address Bit 1

### MAX4534 (Single 4-to-1 Mux)

#### MAX4534 (Single 4-to-1 Mux)

•	•	,
<b>A</b> 0	EN	ON SWITCH
Х	0	None
0	1	NO1
1	1	NO2
0	1	NO3
1	1	NO4
	<b>A0</b> X 0 1 0 1	A0      EN        X      0        0      1        1      1        0      1        1      1        1      1

 $X = Don't care; logic 0: V_{AL} \le +0.8; logic 1: V_{AH} \ge +2.4V$ 

### MAX4535 (Dual 2-to-1 Mux)

A0	EN	СОМА	СОМВ
Х	0	None	None
0	1	NO1A	NO1B
1	1	NO2A	NO2B

 $X = Don't care; logic 0: V_{AL} \le +0.8; logic 1: V_{AH} \ge +2.4V$ 

### **Detailed Description**

The MAX4534/MAX4535 differ considerably from traditional fault-protected multiplexers, offering several advantages. First, they are constructed with two parallel FETs, allowing very low resistance when the switch is on. Second, they allow signals on the NO\_ pins that are within or beyond the supply rails to be passed through the switch to the COM terminal. This allows rail-

# MAX4535 (Dual 2-to-1 Mux)

PIN	NAME	FUNCTION
1	AO	Address Bit 0
2	EN	Enable Input
3	V-	Negative Supply Voltage
4	NO1A	Channel Input 1A (fault protected)
5	NO2A	Channel Input 2A (fault protected)
6, 9, 14	N.C.	No connection
7	COMA	Mux Output A
8	COMB	Mux Output B
10	NO2B	Channel Input 2B (fault protected)
11	NO1B	Channel Input 1B (fault protected)
12	V+	Positive Supply Voltage
13	GND	Ground

to-rail signal operation. Third, when a signal on VNO\_ exceeds the supply rails (i.e., a fault condition), the voltage on COM\_ is limited to the supply rails. Operation is identical for both fault polarities.

When the NO\_ voltage goes beyond supply rails (fault condition), the NO\_ input becomes high impedance regardless of the switch state or load resistance. When power is removed, and the fault protection is still in effect, the NO\_ terminals are a virtual open circuit. The fault can be up to  $\pm 40V$ , with V+ = V- = 0. If the switch is on, the COM\_ output current is furnished from the V+ or V- pin by "booster" FETs connected to each supply pin. These FETs can source or sink up to 10mA.

The COM\_ pins are not fault-protected. If a voltage source is connected to any COM\_ pin, it should be limited to the supply voltages. Exceeding the supply voltage will cause high currents to flow through the ESD protection diodes, damaging the device (see *Absolute Maximum Ratings*).

Figure 1 shows the internal construction, with the analog signal paths shown in bold. A single, normally open (NO) switch is shown. The analog switch is formed by the parallel combination of N-channel FET N1 and P-channel FET P1, which are driven on and off simultaneously, according to the input fault condition and the logic level state.





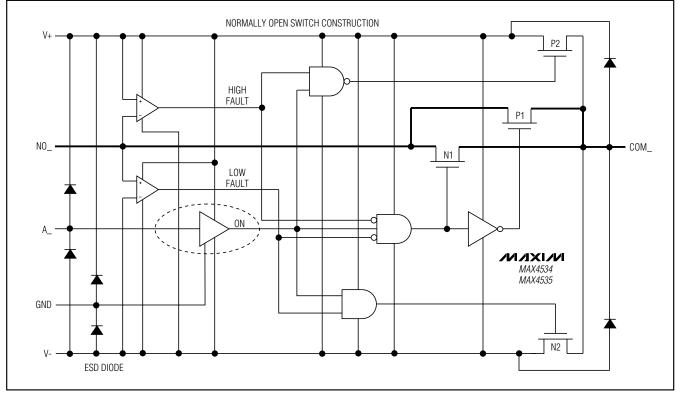


Figure 1. Functional Diagram

#### **NO\_ Input Voltage**

The maximum allowable input voltage for safe operation depends on whether supplies are on or off and on the load configuration at the COM output. If COM is referred to a voltage other than ground, but within the supplies, VNO\_ may range higher or lower than the supplies, provided the absolute value of VNO\_ -VCOM\_ is less than 40V. For example, if the load is referred to +10V at COM\_, then the NO\_ voltage range can be from +50V to -30V. As another example, if the load is connected to -10V at COM\_, the NO\_ voltage range is limited to -50V to +30V.

If the supplies are  $\pm 15V$  and COM is referenced to ground through a load, the maximum NO\_ voltage is  $\pm 36V$ . If the supplies are off and the COM output is referenced to ground, the maximum NO\_ voltage is  $\pm 40V$ .

#### **Normal Operation**

Two comparators continuously compare the voltage on the NO\_ pin with V+ and V- supply voltages. When the signal on NO\_ is between V+ and V-, the multiplexer behaves normally, with FETs N1 and P1 turning on and off in response to A\_ signals (Figure 1). The parallel combination of N1 and P1 forms a low-value resistor between NO\_ and COM\_ so that signals pass equally well in either direction.

#### **Positive Fault Condition**

When the signal on NO\_ exceeds V+ by about 150mV, the positive fault comparator output goes high, turning off FETs N1 and P1 (Figure 1). This makes the NO\_ pin high impedance regardless of the switch state. If the switch state is "off," all FETs turn off, and both NO\_ and COM\_ are high impedance. If the switch state is "on," FET P2 turns on, clamping COM\_ to V+.

#### **Negative Fault Condition**

When the signal on NO\_ goes about 150mV below V-, the negative fault comparator output goes high, turning off FETs N1 and P1 (Figure 1). This makes the NO pin high impedance regardless of the switch state. If the switch state is "off," all FETs turn off, and both NO\_ and COM\_ are high impedance. If the switch state is "on," FET N2 turns on, clamping COM\_ to V-.



#### **Transient Fault Condition**

When a fast rising or falling transient on NO\_ exceeds V+ or V-, the output (COM\_) follows the input (NO\_) to the supply rail with only a few nanoseconds delay. This delay is due to the switch on-resistance and circuit capacitance to ground. When the input transient returns to within the supply rails, however, there is a longer output recovery time. For positive faults, the recovery time is typically 2.5µs. For negative faults, the recovery time is typically 1.3µs. These values depend on the COM\_ output resistance and capacitance. The delays do not depend on the fault amplitude. Higher COM\_ output resistance and capacitance increase the recovery times.

#### **Non-Fault-Protected Pins**

FETs N2 and P2 can source about  $\pm 10$ mA from V+ or V- to the COM\_ pin in the fault condition (Figure 1). Ensure that if the COM\_ pin is connected to a low - impedance load, the 30mA absolute maximum current rating is never exceeded, both in normal and fault conditions.

The GND, COM\_, EN, and A\_ pins do not have fault protection. Reverse ESD protection diodes are internally connected between GND, COM\_, A\_, EN, and both V+ and V-. If a signal on GND, COM\_, EN, or A\_ exceeds V+ or V- by more than 300mV, one of these diodes will conduct. During normal operation, these reverse-biased ESD diodes leak a few nanoamps of current to V+ and V-.

#### **Fault Protection Voltage and Power-Off**

The maximum fault voltage on the NO\_ pins is  $\pm 40V$  from ground when the power is off. With  $\pm 15V$  supply voltages, the highest voltage on NO\_ can be V- + 40V, and the lowest voltage on NO\_ can be V+ - 40V. **Caution: Exceeding these limits can damage the IC.** 

#### **Logic-Level Thresholds**

The logic-level thresholds are CMOS and TTL compatible with  $V_{+} = 4.5V$  to 16.5V.

### **Applications Information**

#### Ground

There is no connection between the analog signal paths and GND. The analog signal paths consist of an N-channel and a P-channel MOSFET with their sources and drains paralleled, and their gates driven out of phase to V+ and V- by the logic-level translators.

V+ and GND power the internal logic and logic-level translators and set the input logic thresholds. The logic-level translators convert the logic levels to switched V+ and V- signals to drive the gates of the channel MOSFETs. This drive signal is the only connection between the power supplies and the analog signals. GND, A\_, EN, and COM\_ have ESD protection diodes to V+ and V-.

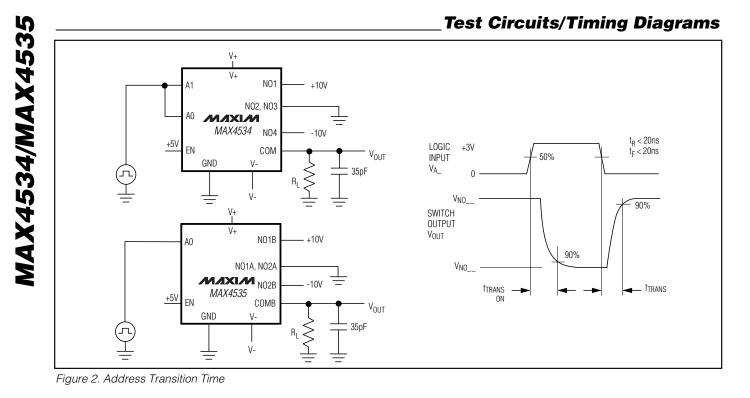
#### **Supply Current Reduction**

When the logic signals are driven rail-to-rail from 0 to +15V or -15V to +15V, the current consumption will be reduced from  $300\mu$ A (typ) to  $180\mu$ A.

#### **Power Supplies**

The MAX4534/MAX4535 operate with bipolar supplies between  $\pm 4.5V$  and  $\pm 20V$ . The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the 44V absolute maximum rating.

The MAX4534/MAX4535 operate from single supplies between +9V and +36V when V- is connected to GND.



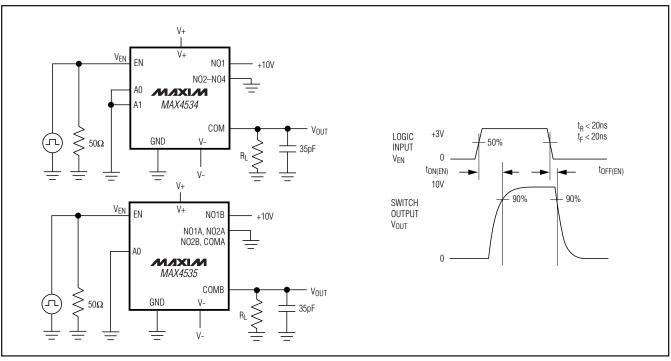


Figure 3. Enable Switching Time

# \_Test Circuits/Timing Diagrams (continued)

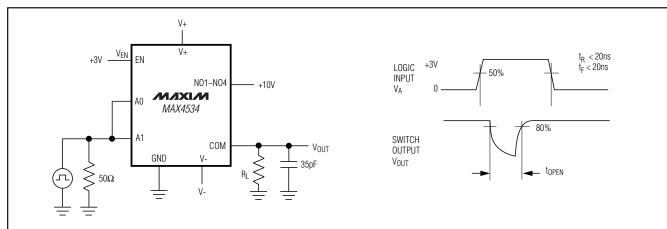


Figure 4. MAX4534 Break-Before-Make Interval

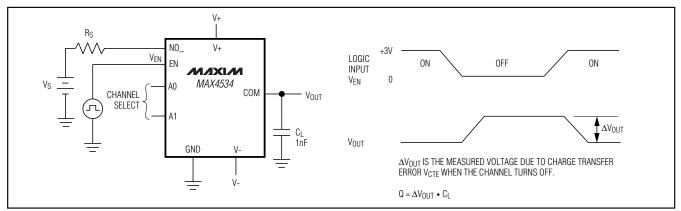
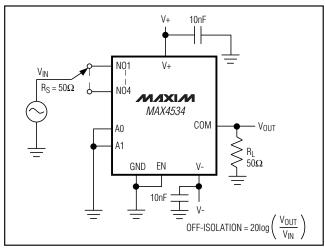
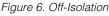
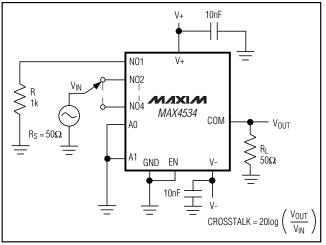


Figure 5. Charge Injection









MAX4534/MAX4535



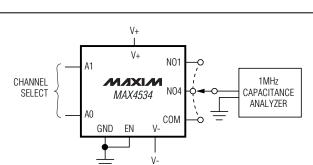


Figure 8. NO\_, COM\_ Capacitance

## **Test Circuits/Timing Diagrams (continued)**

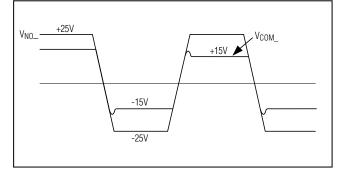


Figure 9. Transient Behavior of Fault Condition

## \_Chip Information

TRANSISTOR COUNT: 265

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

\_\_\_\_\_Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600

© 2005 Maxim Integrated Products Printed USA MAXIM is a registered trademark of Maxim Integrated Products, Inc.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Multiplexer Switch ICs category:

Click to view products by Maxim manufacturer:

Other Similar products are found below :

NLV74HC4066ADR2G HEF4051BP MC74HC4067ADTG DG508AAK/883B NLV14051BDG 016400E PI3V512QE 7705201EC PI2SSD3212NCE PI3L100QE NLAS3257CMX2TCG PI5A3157BC6EX PI3V512QEX PI3DBS16213ZLEX PI3DBS16415ZHEX PS509LEX MUX36S16IRSNR 74LVC1G3157GM-Q10X TC7W53FK,LF CD4053BM96 MC74HC4053ADWR2G MAX4051AEEE+ HEF4053BT.653 PI3L720ZHEX ADG1404YRUZ-REEL7 ADG1208YRZ-REEL7 MAX4704EUB+T ADG1406BRUZ-REEL7 CD4053BPWRG4 ADG658TRUZ-EP 74HC4053D.653 74HCT4052PW.118 74LVC2G53DP.125 74HC4052DB.112 74HC4052PW.112 74HC4053DB.112 74HC4067DB.112 74HC4351DB.112 74HCT4052D.112 74HCT4052DB.112 74HCT4351D.112 74LV4051PW.112 FSA1256L8X\_F113 PI5V330QE PI5V331QE 5962-8771601EA 5962-87716022A ADG5249FBRUZ ADG1438BRUZ ADG5207BCPZ-RL7